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# Dual Non-Inverting Schmitt Trigger Buffer

## MC74VHC2G17, MC74VHC2GT17

The MC74VHC2G17/MC74VHC2GT17 is a high performance dual buffer with Schmitt-Trigger inputs operating from a 2.0 to 5.5 V supply. The MC74VHC2G17 has CMOS-level input thresholds while the MC74VHC2GT17 has TTL-level input thresholds.

### Features

- Designed for 2.0 V to 5.5 V  $V_{CC}$  Operation
- 4.0 ns  $t_{PD}$  at  $V_{CC} = 5$  V (Typ)
- Inputs/Outputs Overvoltage Tolerant up to 5.5 V
- $I_{OFF}$  Supports Partial Power Down Protection
- Sink 8 mA at 4.5 V
- Available in SC-88, SC-74, and UDFN6 Packages
- Chip Complexity < 100 FETs
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

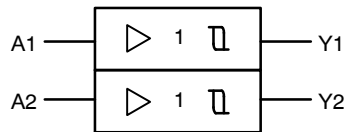

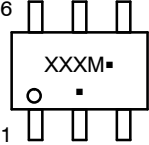

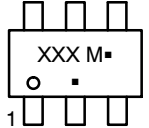








Figure 1. Logic Symbol



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		MARKING DIAGRAMS
	SC-88 DF SUFFIX CASE 419B-02	
	SC-74 CASE 318F-05	
	UDFN6 1.45x1.0, 0.5P CASE 517AQ	
	UDFN6 1.2 x 1.0 CASE 517AA	
	UDFN6 1x1, 0.35P CASE 517BX	

X, XXX = Specific Device Code  
M = Date Code\*  
▪ = Pb-Free Package

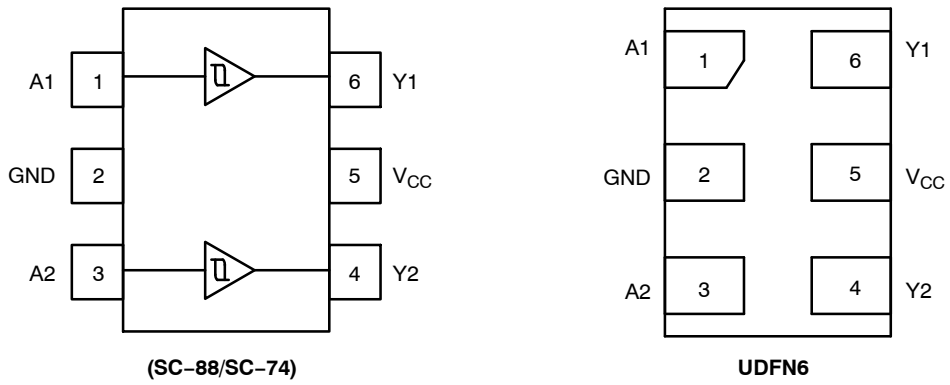
(Note: Microdot may be in either location)

\*Date Code orientation and/or position may vary depending upon manufacturing location.

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

## MC74VHC2G17, MC74VHC2GT17



**Figure 2. Pinout (Top View)**

### PIN ASSIGNMENT

Pin	Function
1	A1
2	GND
3	A2
4	Y2
5	V <sub>CC</sub>
6	Y1

### FUNCTION TABLE

A Input	Y Output
L	L
H	H

# MC74VHC2G17, MC74VHC2GT17

## MAXIMUM RATINGS

Symbol	Characteristics	Value	Units
$V_{CC}$	DC Supply Voltage	-0.5 to +6.5	V
$V_{IN}$	DC Input Voltage	-0.5 to +6.5	V
$V_{OUT}$	DC Output Voltage SC-88, SC-74, UDFN6 Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode ( $V_{CC} = 0$ V)	-0.5 to $V_{CC} + 0.5$ -0.5 to +6.5 -0.5 to +6.5	V
$I_{IK}$	DC Input Diode Current, $V_{IN} < GND$	-20	mA
$I_{OK}$	DC Output Diode Current, $V_{OUT} < GND$	-20	mA
$I_{OUT}$	DC Output Source/Sink Current	$\pm 25$	mA
$I_{CC}$ or $I_{GND}$	DC Supply Current per Supply Pin or Ground Pin	$\pm 50$	mA
$T_{STG}$	Storage Temperature Range	-65 to +150	$^{\circ}C$
$T_L$	Lead Temperature, 1 mm from Case for 10 secs	260	$^{\circ}C$
$T_J$	Junction Temperature under Bias	+150	$^{\circ}C$
$\theta_{JA}$	Thermal Resistance (Note 2)	SC-88 SC-74 UDFN6 377 320 154	$^{\circ}C/W$
$P_D$	Power Dissipation in Still Air	SC-88 SC-74 UDFN6 332 390 812	mW
MSL	Moisture Sensitivity	Level 1	-
$F_R$	Flameability Rating	Oxygen Index: 28 to 34 UL 94-V-0 @ 0.125 in	-
$V_{ESD}$	ESD Withstand Voltage (Note 3)	Human Body Model Charged Device Model 2000 1000	V
$I_{LATCHUP}$	Latchup Performance (Note 4)	$\pm 100$	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Applicable to devices with outputs that may be tri-stated.
2. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow per JESD51-7.
3. HBM tested to ANSI/ESDA/JEDEC JS-001-2017. CDM tested to EIA/JESD22-C101-F. JEDEC recommends that ESD qualification to EIA/JESD22-A115-A (Machine Model) be discontinued per JEDEC/JEP172A.
4. Tested to EIA/JESD78 Class II.

## RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
$V_{CC}$	Positive DC Supply Voltage	2.0	5.5	V
$V_{IN}$	DC Input Voltage	0	5.5	V
$V_{OUT}$	DC Output Voltage Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode ( $V_{CC} = 0$ V)	0 0 0	$V_{CC}$ 5.5 5.5	V
$T_A$	Operating Temperature Range	-55	+125	$^{\circ}C$
$t_r, t_f$	Input Transition Rise or Fall Rate $V_{CC} = 2.0$ V $V_{CC} = 2.3$ V to 2.7 V $V_{CC} = 3.0$ V to 3.6 V $V_{CC} = 4.5$ V to 5.5 V	0 0 0 0	No Limit No Limit No Limit No Limit	ns

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

# MC74VHC2G17, MC74VHC2GT17

## DC ELECTRICAL CHARACTERISTICS (MC74VHC2G17)

Symbol	Parameter	Test Conditions	V <sub>CC</sub> (V)	T <sub>A</sub> = 25°C			-40°C ≤ T <sub>A</sub> ≤ 85°C		-55°C ≤ T <sub>A</sub> ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
V <sub>T+</sub>	Positive Threshold Voltage		3.0	-	2.0	2.20	-	2.20	-	2.20	V
			4.5	-	3.0	3.15	-	3.15	-	3.15	
			5.5	-	3.6	3.85	-	3.85	-	3.85	
V <sub>T-</sub>	Negative Threshold Voltage		3.0	0.9	1.5	-	0.9	-	0.9	-	V
			4.5	1.35	2.3	-	1.35	-	1.35	-	
			5.5	1.65	2.9	-	1.65	-	1.65	-	
V <sub>H</sub>	Hysteresis Voltage		3.0	0.30	0.57	1.20	0.30	1.20	0.30	1.20	V
			4.5	0.40	0.67	1.40	0.40	1.40	0.40	1.40	
			5.5	0.50	0.74	1.60	0.50	1.60	0.50	1.60	
V <sub>OH</sub>	High-Level Output Voltage	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	2.0	1.9	2.0	-	1.9	-	1.9	-	V
		I <sub>OH</sub> = -50 μA	3.0	2.9	3.0	-	2.9	-	2.9	-	
		I <sub>OH</sub> = -50 μA	4.5	4.4	4.5	-	4.4	-	4.4	-	
		I <sub>OH</sub> = -4 mA	3.0	2.58	-	-	2.48	-	2.34	-	
		I <sub>OH</sub> = -8 mA	4.5	3.94	-	-	3.80	-	3.66	-	
V <sub>OL</sub>	Low-Level Output Voltage	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	2.0	-	0.0	0.1	-	0.1	-	0.1	V
		I <sub>OL</sub> = 50 μA	3.0	-	0.0	0.1	-	0.1	-	0.1	
		I <sub>OL</sub> = 50 μA	4.5	-	0.0	0.1	-	0.1	-	0.1	
		I <sub>OL</sub> = 4 mA	3.0	-	-	0.36	-	0.44	-	0.52	
		I <sub>OL</sub> = 8 mA	4.5	-	-	0.36	-	0.44	-	0.52	
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	2.0 to 5.5	-	-	±0.1	-	±1.0	-	±1.0	μA
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0	-	-	1.0	-	10	-	10	μA
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	-	-	1.0	-	20	-	40	μA

# MC74VHC2G17, MC74VHC2GT17

## DC ELECTRICAL CHARACTERISTICS (MC74VHC2GT17)

Symbol	Parameter	Test Conditions	V <sub>CC</sub> (V)	T <sub>A</sub> = 25°C			-40°C ≤ T <sub>A</sub> ≤ 85°C		-55°C ≤ T <sub>A</sub> ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
V <sub>T+</sub>	Positive Threshold Voltage		3.0	-	1.40	1.60	-	1.6	-	1.6	V
			4.5	-	1.74	2.00	-	2.0	-	2.0	
			5.5	-	1.94	2.10	-	2.1	-	2.1	
V <sub>T-</sub>	Negative Threshold Voltage		3.0	0.35	0.76	-	0.35	-	0.35	-	V
			4.5	0.5	1.01	-	0.5	-	0.5	-	
			5.5	0.6	1.13	-	0.6	-	0.6	-	
V <sub>H</sub>	Hysteresis Voltage		3.0	0.30	0.64	1.20	0.30	1.20	0.30	1.20	V
			4.5	0.40	0.73	1.40	0.40	1.40	0.40	1.40	
			5.5	0.50	0.81	1.60	0.50	1.60	0.50	1.60	
V <sub>OH</sub>	High-Level Output Voltage	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	2.0	1.9	2.0	-	1.9	-	1.9	-	V
		I <sub>OH</sub> = -50 μA	3.0	2.9	3.0	-	2.9	-	2.9	-	
		I <sub>OH</sub> = -50 μA	4.5	4.4	4.5	-	4.4	-	4.4	-	
		I <sub>OH</sub> = -4 mA	3.0	2.58	-	-	2.48	-	2.34	-	
		I <sub>OH</sub> = -8 mA	4.5	3.94	-	-	3.80	-	3.66	-	
V <sub>OL</sub>	Low-Level Output Voltage	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	2.0	-	0.0	0.1	-	0.1	-	0.1	V
		I <sub>OL</sub> = 50 μA	3.0	-	0.0	0.1	-	0.1	-	0.1	
		I <sub>OL</sub> = 50 μA	4.5	-	0.0	0.1	-	0.1	-	0.1	
		I <sub>OL</sub> = 4 mA	3.0	-	-	0.36	-	0.44	-	0.52	
		I <sub>OL</sub> = 8 mA	4.5	-	-	0.36	-	0.44	-	0.52	
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	2.0 to 5.5	-	-	±0.1	-	±1.0	-	±1.0	μA
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0	-	-	1.0	-	10	-	10	μA
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = V <sub>CC</sub> or GND	5.5	-	-	1.0	-	20	-	40	μA
I <sub>CC(T)</sub>	Increase in Quiescent Supply Current per Input Pin	One Input: V <sub>IN</sub> = 3.4 V; Other Input at V <sub>CC</sub> or GND	5.5	-	-	1.35	-	1.5	-	1.65	mA

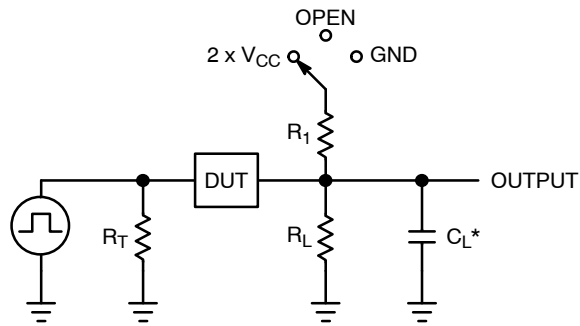
## AC ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Conditions	V <sub>CC</sub> (V)	T <sub>A</sub> = 25°C			-40°C ≤ T <sub>A</sub> ≤ 85°C		-55°C ≤ T <sub>A</sub> ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
t <sub>PLH</sub> , t <sub>PHL</sub>	Propagation Delay, A to Y (Figures 3 and 4)	C <sub>L</sub> = 15 pF	3.0 to 3.6	-	7.0	12.8	-	15.0	-	17.0	ns
				-	8.5	16.3	-	18.5	-	20.5	
		C <sub>L</sub> = 50 pF	4.5 to 5.5	-	4.0	8.6	-	10.0	-	11.5	
				-	5.5	10.6	-	12.0	-	13.5	
C <sub>IN</sub>	Input Capacitance			-	4.0	10	-	10	-	10	pF
C <sub>OUT</sub>	Output Capacitance	Output in High Impedance State		-	6.0	-	-	-	-	-	pF

C <sub>PD</sub>	Power Dissipation Capacitance (Note 5)	<b>Typical @ 25°C, V<sub>CC</sub> = 5.0 V</b>	pF
		8.0	

5. C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no-load dynamic power consumption; P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.

# MC74VHC2G17, MC74VHC2GT17

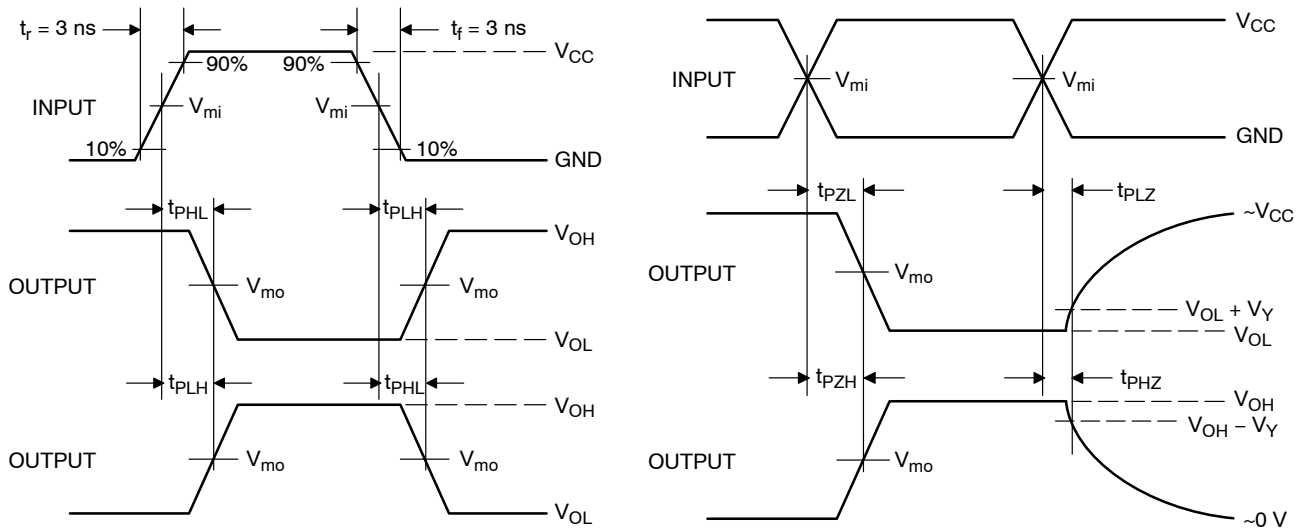


$C_L$  includes probe and jig capacitance  
 $R_T$  is  $Z_{OUT}$  of pulse generator (typically 50  $\Omega$ )  
 $f = 1$  MHz

**Figure 3. Test Circuit**

Test	Switch Position	$C_L$ , pF	$R_L$ , $\Omega$
$t_{PLH} / t_{PHL}$	Open	See AC Characteristics Table	X
$t_{PLZ} / t_{PZL}$	$V_{CC}$		1 k
$t_{PHZ} / t_{PZH}$	GND		1 k

X = Don't Care



**Figure 4. Switching Waveforms**

$V_{CC}$ , V	$V_{mi}$ , V	$V_{mo}$ , V		$V_Y$ , V
		$t_{PLH}$ , $t_{PHL}$	$t_{PZL}$ , $t_{PLZ}$ , $t_{PZH}$ , $t_{PHZ}$	
3.0 to 3.6	$V_{CC} / 2$	$V_{CC} / 2$	$V_{CC} / 2$	0.3
4.5 to 5.5	$V_{CC} / 2$	$V_{CC} / 2$	$V_{CC} / 2$	0.3

# MC74VHC2G17, MC74VHC2GT17

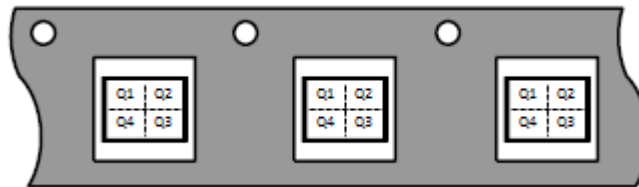
## ORDERING INFORMATION

Device	Package	Specific Device Code	Pin1 Orientation (See below)	Shipping <sup>†</sup>
MC74VHC2G17DFT2G (In Development)	SC-88	TBD	Q4	3000 / Tape & Reel
MC74VHC2G17DBVT1G (In Development)	SC-74	TBD	Q4	3000 / Tape & Reel
MC74VHC2G17MU2TCG (In Development)	UDFN6, 1.2 x 1.0, 0.4P	A	Q4	3000 / Tape & Reel
MC74VHC2G17MU1TCG (In Development)	UDFN6, 1.45 x 1.0, 0.5P	R (Rotated 90° CW)	Q4	3000 / Tape & Reel
MC74VHC2G17MU3TCG (In Development)	UDFN6, 1.0 x 1.0, 0.35P	5 (Rotated 90° CW)	Q4	3000 / Tape & Reel
MC74VHC2GT17DFT2G (In Development)	SC-88	TBD	Q4	3000 / Tape & Reel
MC74VHC2GT17DBVT1G (In Development)	SC-74	TBD	Q4	3000 / Tape & Reel
MC74VHC2GT17MU1TCG (In Development)	UDFN6, 1.45 x 1.0, 0.5P	TBD	Q4	3000 / Tape & Reel
MC74VHC2GT17MU3TCG (In Development)	UDFN6, 1.0 x 1.0, 0.35P	TBD	Q4	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

### Pin 1 Orientation in Tape and Reel

Direction of Feed

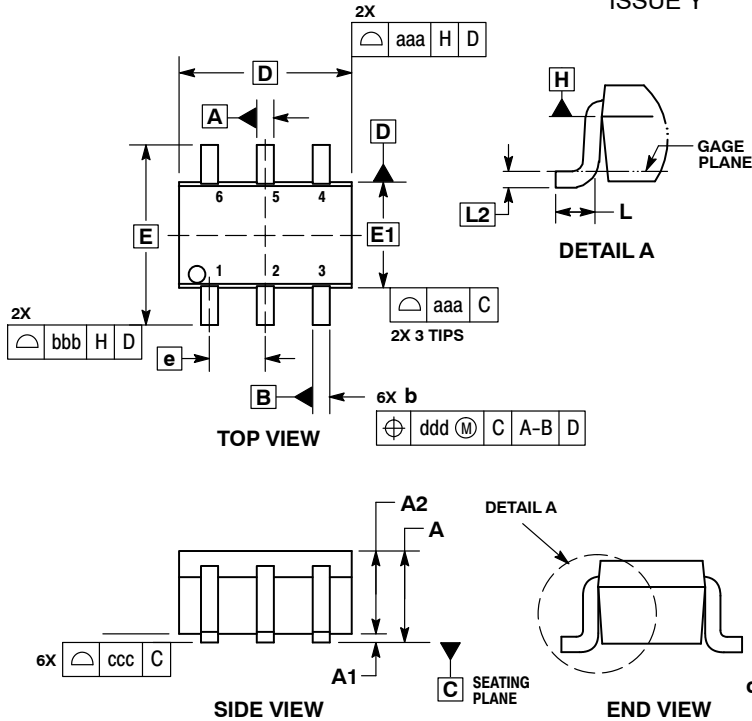




# MC74VHC2G17, MC74VHC2GT17

## PACKAGE DIMENSIONS

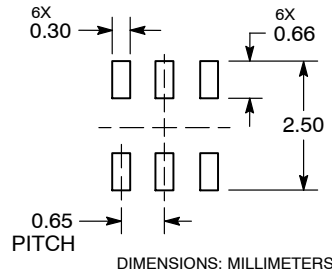
SC-88/SC70-6/SOT-363  
CASE 419B-02  
ISSUE Y



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.20 PER END.
  4. DIMENSIONS D AND E1 AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY AND DATUM H.
  5. DATUMS A AND B ARE DETERMINED AT DATUM H.
  6. DIMENSIONS b AND c APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.08 AND 0.15 FROM THE TIP.
  7. DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 TOTAL IN EXCESS OF DIMENSION b AT MAXIMUM MATERIAL CONDITION. THE DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OF THE FOOT.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	---	---	1.10	---	---	0.043
A1	0.00	---	0.10	0.000	---	0.004
A2	0.70	0.90	1.00	0.027	0.035	0.039
b	0.15	0.20	0.25	0.006	0.008	0.010
C	0.08	0.15	0.22	0.003	0.006	0.009
D	1.80	2.00	2.20	0.070	0.078	0.086
E	2.00	2.10	2.20	0.078	0.082	0.086
E1	1.15	1.25	1.35	0.045	0.049	0.053
e	0.65 BSC			0.026 BSC		
L	0.26	0.36	0.46	0.010	0.014	0.018
L2	0.15 BSC			0.006 BSC		
aaa	0.15			0.006		
bbb	0.30			0.012		
ccc	0.10			0.004		
ddd	0.10			0.004		

### RECOMMENDED SOLDERING FOOTPRINT\*

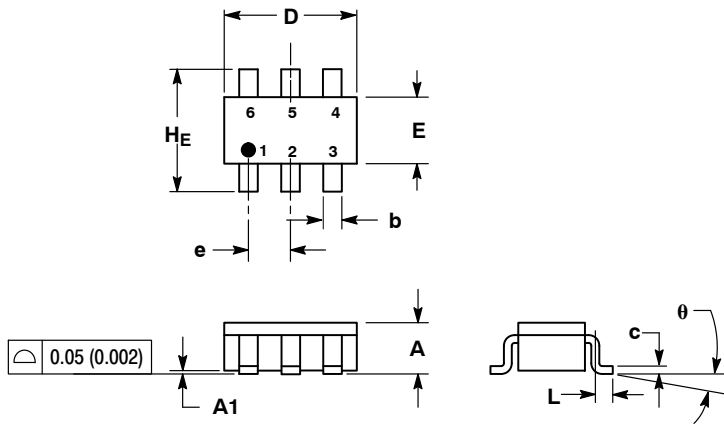


\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# MC74VHC2G17, MC74VHC2GT17

## PACKAGE DIMENSIONS

SC-74  
CASE 318F-05  
ISSUE N

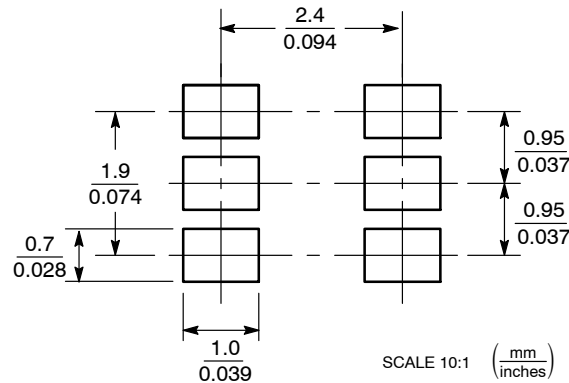


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. 318F-01, -02, -03, -04 OBSOLETE. NEW STANDARD 318F-05.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	0.90	1.00	1.10	0.035	0.039	0.043
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.25	0.37	0.50	0.010	0.015	0.020
c	0.10	0.18	0.26	0.004	0.007	0.010
D	2.90	3.00	3.10	0.114	0.118	0.122
E	1.30	1.50	1.70	0.051	0.059	0.067
e	0.95	0.95	1.05	0.037	0.037	0.041
L	0.20	0.40	0.60	0.008	0.016	0.024
HE	2.50	2.75	3.00	0.099	0.108	0.118
theta		-			-	

### SOLDERING FOOTPRINT\*

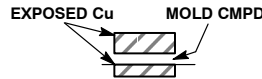
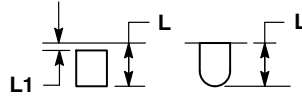


\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# MC74VHC2G17, MC74VHC2GT17

## PACKAGE DIMENSIONS

UDFN6, 1.45x1.0, 0.5P  
CASE 517AQ  
ISSUE O



**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM THE TERMINAL TIP.

MILLIMETERS		
DIM	MIN	MAX
A	0.45	0.55
A1	0.00	0.05
A2	0.07	REF
b	0.20	0.30
D	1.45	BSC
E	1.00	BSC
e	0.50	BSC
L	0.30	0.40
L1	---	0.15



### MOUNTING FOOTPRINT



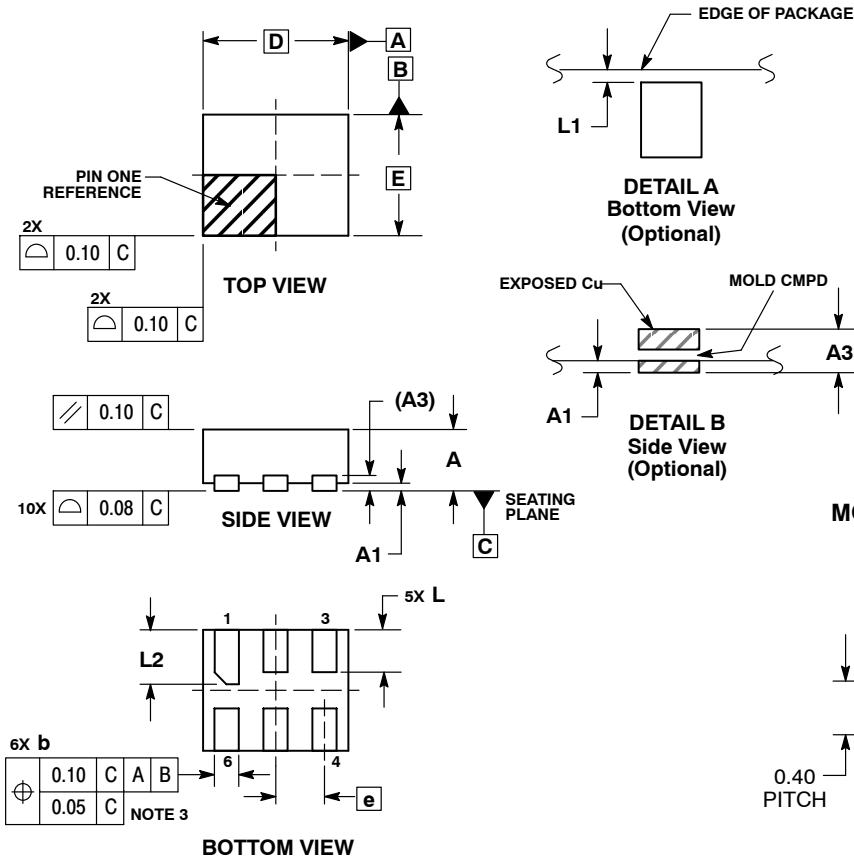
DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# MC74VHC2G17, MC74VHC2GT17

## PACKAGE DIMENSIONS

UDFN6, 1.2x1.0, 0.4P  
CASE 517AA-01  
ISSUE D

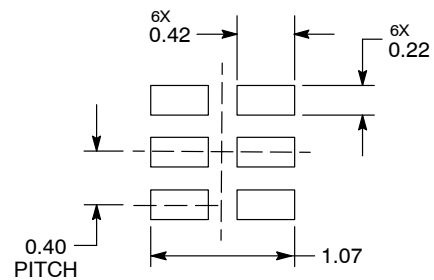


**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.25 AND 0.30 mm FROM TERMINAL.
4. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

MILLIMETERS		
DIM	MIN	MAX
A	0.45	0.55
A1	0.00	0.05
A3	0.127	REF
b	0.15	0.25
D	1.20	BSC
E	1.00	BSC
e	0.40	BSC
L	0.30	0.40
L1	0.00	0.15
L2	0.40	0.50

**MOUNTING FOOTPRINT\***



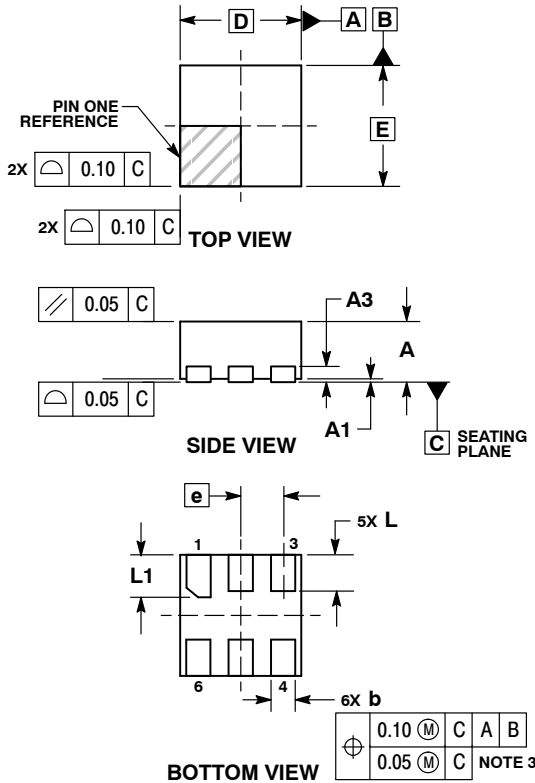
DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# MC74VHC2G17, MC74VHC2GT17

## PACKAGE DIMENSIONS

UDFN6, 1x1, 0.35P  
CASE 517BX  
ISSUE O

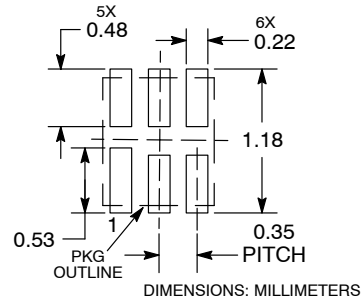


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
4. PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

MILLIMETERS		
DIM	MIN	MAX
A	0.45	0.55
A1	0.00	0.05
A3	0.13 REF	
b	0.12	0.22
D	1.00 BSC	
E	1.00 BSC	
e	0.35 BSC	
L	0.25	0.35
L1	0.30	0.40

### RECOMMENDED SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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